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Optimization of dye adsorption time and film thickness for efficient ZnO dye-sensitized solar cells with high at-rest stability

Wei-Chen Chang^{1,2}, Chia-Hua Lee², Wan-Chin Yu^{1*} and Chun-Min Lin¹

Abstract

Photoelectrodes for dye-sensitized solar cells were fabricated using commercially available zinc oxide (ZnO) nanoparticles and sensitized with the dye N719. This study systematically investigates the effects of two fabrication factors: the ZnO film thickness and the dye adsorption time. Results show that these two fabrication factors must be optimized simultaneously to obtain efficient ZnO/N719-based cells. Different film thicknesses require different dye adsorption times for optimal cell performance. This is because a prolonged dye adsorption time leads to a significant deterioration in cell performance. This is contrary to what is normally observed for titanium dioxide-based cells. The highest overall power conversion efficiency obtained in this study was 5.61%, which was achieved by 26- μm -thick photoelectrodes sensitized in a dye solution for 2 h. In addition, the best-performing cell demonstrated remarkable at-rest stability despite the use of a liquid electrolyte. Approximately 70% of the initial efficiency remained after more than 1 year of room-temperature storage in the dark. To better understand how dye adsorption time affects electron transport properties, this study also investigated cells based on 26- μm -thick films using electrochemical impedance spectroscopy (EIS). The EIS results show good agreement with the measured device performance parameters.

Keywords: Zinc oxide, Dye-sensitized solar cells, Dye adsorption time, Film thickness, Conversion efficiency, At-rest stability, Electrochemical impedance spectroscopy

Background

Dye-sensitized solar cells (DSSCs) are regarded as promising low-cost solar cells with high light-to-energy conversion efficiency. Systems based on titanium dioxide (TiO_2) nanoparticle films sensitized with ruthenium (Ru)-based dyes have achieved a light-to-energy conversion efficiency of more than 11% [1,2]. Other metal oxides, including tin dioxide, indium (III) oxide, niobium pentoxide, and zinc oxide (ZnO), have also been used as photoelectrode materials [3-5]. Among these materials, ZnO has attracted considerable attention because it has an energy-band structure similar to that of TiO_2 but possesses a higher electron mobility and allows more flexibility in synthesis and morphologies [6,7].

The photovoltaic performance of a DSSC relies on the characteristics of its photoanode, which plays a central role in converting light into electrical energy. A DSSC photoanode typically consists of a mesoporous oxide film on a transparent conducting glass substrate. Dye molecules that capture photons from light during device operation are attached to the surface of oxide film. Photoexcitation of the dye molecules leads to the injection of electrons into the oxide film. Therefore, an oxide film with a large interfacial surface area and superior electron transport properties is vital for strong light harvesting and efficient device performance. Consequently, numerous researchers have attempted to develop novel nanostructures with these desirable properties [8-12]. Another important strategy that has been widely adopted in DSSCs to boost optical absorption is light scattering [13]. The basic principle of the light scattering method is to confine light propagation and extend the traveling distance of light within the oxide film. In this

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way, the opportunity of photon absorption by the dye molecules is increased, so is the cell conversion efficiency. In traditional DSSCs, the porous photoelectrode typically consists of nanocrystallites of approximately 20 nm in diameter to ensure a large interfacial surface area; to generate light scattering, submicron-sized particles are incorporated into the nanocrystalline film. These submicron-sized light scatterers can either be mixed into the nanocrystalline film [14,15] or form a scattering layer on the top of the nanocrystalline film [16-20]. In addition to submicron-sized particles, some other nanostructures, such as nanowires [21-23] and nanotubes [24,25] have also been studied as light scatterers in DSSCs. Recently, a promising three-dimensional nanostructure that has been developed to fulfill multiple functions in DSSCs is nanocrystallite aggregates [26-29]. These aggregates not only provide a large interfacial surface area, but also generate light scattering because they are composed of nanoparticles that assemble into submicron aggregates. Employing nanocrystallite aggregates can avoid the drawbacks of using large particles as light scatterers in conventional DSSCs. Mixing the large particles into the nanocrystalline film unavoidably causes a decrease in the interfacial surface area of the film, whereas placing the large particles on top of the nanocrystalline film brings about a limited increase in the interfacial surface area of the film.

Regardless of the film nanoarchitecture employed, film thickness and dye adsorption time are two important factors that must be considered during photoanode fabrication. Increasing the total interfacial surface area of the porous film by raising the film thickness is simple, which boosts the amount of dye adsorbed and, thus, light absorption. Thus, raising the film thickness can increase the short-current density (J_{SC}) [21,30]. However, a thick film also aggravates unwanted charge recombination and poses more restrictions on mass transfer. Consequently, both the open-current voltage (V_{OC}) and overall conversion efficiency decline [14,21,30,31]. Therefore, film thickness must be optimized to obtain efficient cells.

Another key fabrication factor is the dye adsorption time, which determines the quantity and the nature of the adsorbed dye molecules. The dye adsorption time should be sufficiently long so that the interfacial surface of the oxide film is completely covered with a monolayer of dye molecules. In fabricating TiO_2 -based photoanodes, the length of the dye adsorption time is first determined and then applied to all film thicknesses during the subsequent thickness optimization process [32-34]. This is because TiO_2 is insensitive to prolonged sensitization times because of its higher chemical stability. Conversely, a prolonged dye adsorption time in ZnO-based photoanodes often significantly deteriorates cell performance. Thus, varying film thicknesses may require different dye adsorption times for

optimal cell performance. Compared to TiO_2 , ZnO is less stable with acidic dyes, such as Ru-based N3 and N719 dyes. The formation of Zn^{2+} /dye aggregates is a result of ZnO dissolution in these acidic dye solutions [32,35-37]. The formation of dye aggregates has also been reported for indoline dyes [38]. Ideally, the oxide surface should be covered with a monolayer of dye molecules to achieve efficient electron injection. When dye molecules undergo aggregation, electron injection becomes less efficient, and overall conversion efficiency declines. However, Yan et al. [39], on the other hand, observe the surface etching of ZnO nanoflowers after a long sensitization time. Surface etching also leads to a significant loss in overall conversion efficiency. For ZnO-based cells, it is essential to optimize the dye adsorption time to minimize the formation of dye aggregates and the damage to ZnO surfaces. Because the dye molecules must penetrate the mesoporous oxide film before they attach to the interfacial surface, the optimal dye adsorption time likely depends on the thickness of the ZnO film. Thus, this study investigates both the film thickness and the dye adsorption time. Although these two factors have been individually investigated before and certain studies have reported the influences of dye concentration and adsorption time on DSSC performance [32,36], a detailed and systemic study of the effects of film thickness and dye adsorption time for ZnO-based DSSCs is lacking.

This study reports the preparation of DSSC photoelectrodes using commercially available ZnO nanoparticles sensitized with the acidic N719 dye. This study also systematically investigates the influences of ZnO film thickness and dye adsorption time on the performance of the resulting DSSCs. To further understand the effect of dye adsorption time, electrochemical impedance spectroscopy (EIS) was used to investigate the electron transport characteristics of the fabricated cells. This study shows the correlation between J_{SC} and dye loading as a function of the dye adsorption time and reports the at-rest stability of the best-performing cell.

Methods

Fabrication of solar cells

ZnO films (active area 0.28 cm^2) of various thicknesses (14 to $35\text{ }\mu\text{m}$) were deposited on fluorine-doped tin oxide (FTO) substrates ($8\text{ to }10\text{ }\Omega/\square$, 3 mm in thickness, Nippon Sheet Glass Co. Ltd, Tokyo, Japan) by screen printing. Screen-printable ZnO paste was prepared by dispersing commercially available ZnO nanoparticles (UniRegion Bio-Tech, Taiwan) in an equal proportion of α -terpineol (Fluka, Sigma-Aldrich, St. Louis, MO, USA) and ethyl cellulose. Before dye adsorption, the ZnO films were sintered at 400°C for 1 h to remove any organic material in the paste. This thermal treatment sintered the nanoparticles together to form an interconnecting network.

Dye sensitization was achieved by immersing the sintered ZnO films in a 0.5 mM solution of *cis*-diisothiocyanato-bis(2,2'-bipyridyl-4,4'-dicarboxylato)-ruthenium(II) bis (tetrabutylammonium) (N719, Solaronix; Solaronix SA, Aubonne, Switzerland). The solvent used to prepare the dye solution consisted of equal parts of acetonitrile and *tert*-butanol. Dye sensitization was performed at room temperature, and the adsorption time varied from 0.5 to 4.5 h. The electrodes loaded with the N719 dye were then washed with acetonitrile and dried in air. Platinum (Pt)-coated FTO glass (Nippon Sheet Glass, 8–10 Ω/\square , 3 mm in thickness) served as the counter electrode, which was prepared by placing a drop of H_2PtCl_6 solution on an FTO glass and subsequently sintering the glass at 400°C for 20 min. The ZnO photoanode and the counter electrode were sealed together with a 60- μm -thick hot-melting spacer (Surlyn, DuPont, Wilmington, DE, USA), and the inner space was filled with a volatile electrolyte. The electrolyte was composed of 0.1 M lithium iodide, 0.6 M 1,2-dimethyl-3-propylimidazolium iodide (PMIL, Merk Ltd., Taipei, Taiwan), 0.05 M I_2 (Sigma-Aldrich), and 0.5 M *tert*-butylpyridine (Sigma-Aldrich) in acetonitrile.

Characterization

The morphologies of the ZnO nanoparticle films were examined by field-emission scanning electron microscopy (FE-SEM; Nova230, FEI Co., Hillsboro, OR, USA). The crystalline phases of the ZnO films were determined by X-ray diffraction (XRD) using a diffractometer (X'Pert PRO, PANalytical B.V., Almelo, The Netherlands) with Cu K α radiation. The thickness of the ZnO nanoparticle film was measured using a microfigure-measuring instrument (Surfcorder ET3000, Kosaka Laboratory Ltd., Tokyo, Japan). Dye loading of the photoelectrode was estimated by desorbing the dye in a 10 mM NaOH aqueous solution and then measuring the absorbance of the solution using UV-vis spectroscopy (V-570, Jasco Inc., Easton, MD, USA). Photovoltaic characterization was performed under a white light source (YSS-100A, Yamashita Denso Company, Tokyo, Japan) with an irradiance of 100 mW cm^{-2} at an equivalent air mass (AM) of 1.5 on the surface of the solar cell. The irradiance of the simulated light was calibrated using a silicon photodiode (BS-520, Bunko Keiki Co., Ltd, Tokyo, Japan). Current-voltage (*J*-*V*) curves were recorded with a PGSTAT 30 potentiostat/galvanostat (Autolab, Eco-Chemie, Utrecht, The Netherlands). The evolution of the electron transport process in the cell was investigated using EIS, and the impedance measurements were performed under AM 1.5 G illumination. The applied DC bias voltage and AC amplitude were set at open circuit voltage (V_{OC}) of the cell and 10 mV between the working and the counter electrodes, respectively. The frequency range extended

from 10^{-2} to 10^5 Hz. The electrochemical impedance spectra were recorded using an electrochemical analyzer (Autolab PGSTAT30, Eco-Chemie) and analyzed using Z-view software with the aid of an equivalent circuit.

Results and discussion

Characteristics of ZnO films

Mesoporous films composed of commercial ZnO nanoparticles were prepared by screen printing. The as-printed films were sintered at 400°C for 1 h before dye sensitization to remove organic materials in the screen-printing paste. The FE-SEM image in Figure 1 provides a typical top view of the sintered ZnO film, which is uniform and highly porous. This figure also shows that the ZnO particles in the film have two sizes: most are approximately 20 nm in diameter, whereas some are rod-shaped and have an average dimension of 200 \times 500 nm. Because of their sizes, these rod-shaped particles can serve as light scatterers in the visible region of incident light, enhancing light harvesting in the resulting device [14,15,22].

Figure 2 shows XRD patterns of the ZnO films before and after sintering. These two samples exhibited similar patterns except for differences in the peak intensity. Apart from those corresponding to the FTO substrate, the diffraction peaks can be indexed to the hexagonal wurtzite ZnO (JCPDS card no. 79-0206). No other diffraction peaks were found in both cases, indicating that the prepared ZnO films are of the pure wurtzite phase, and no phase transformation occurs during thermal treatment. The diffraction peaks of the ZnO film became shaper after sintering, implying that the thermal treatment raised the crystallinity of the ZnO

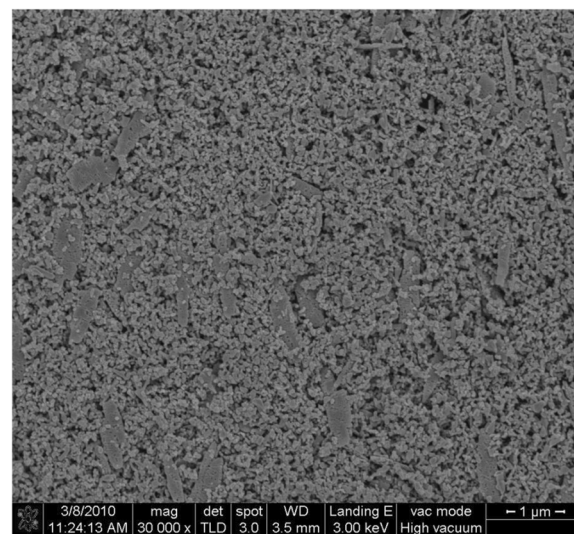
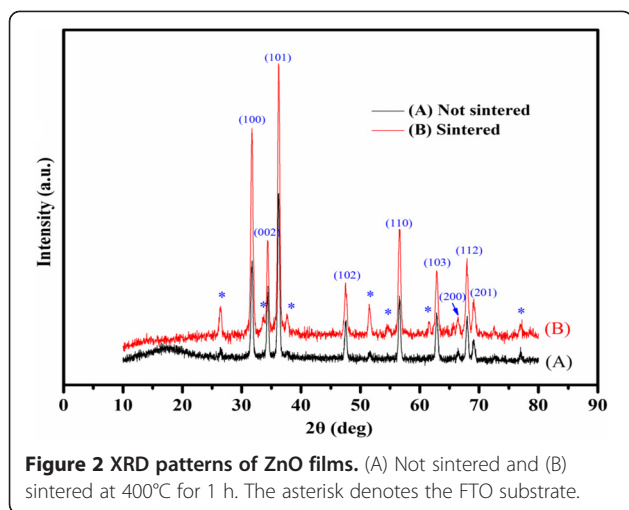


Figure 1 Typical FE-SEM image of sintered ZnO film on FTO substrate.



film. Based on the XRD data, average crystallite size was estimated using the Scherrer's equation:

$$D = \frac{0.89\lambda}{B \cos \theta}, \quad (1)$$

where 0.89 is the Debye-Scherrer's constant, λ is the X-ray wavelength (0.15406 nm), θ is the Bragg's angle (measured in radians) at which the peak is observed, and B is the full width at half maximum. The crystallite sizes before and after sintering, as estimated from major reflections, were both approximately 20 nm. The results show that sintering did not have a significant effect on crystallite size. The estimated crystallite size matched the size of the nanoparticles in the film.

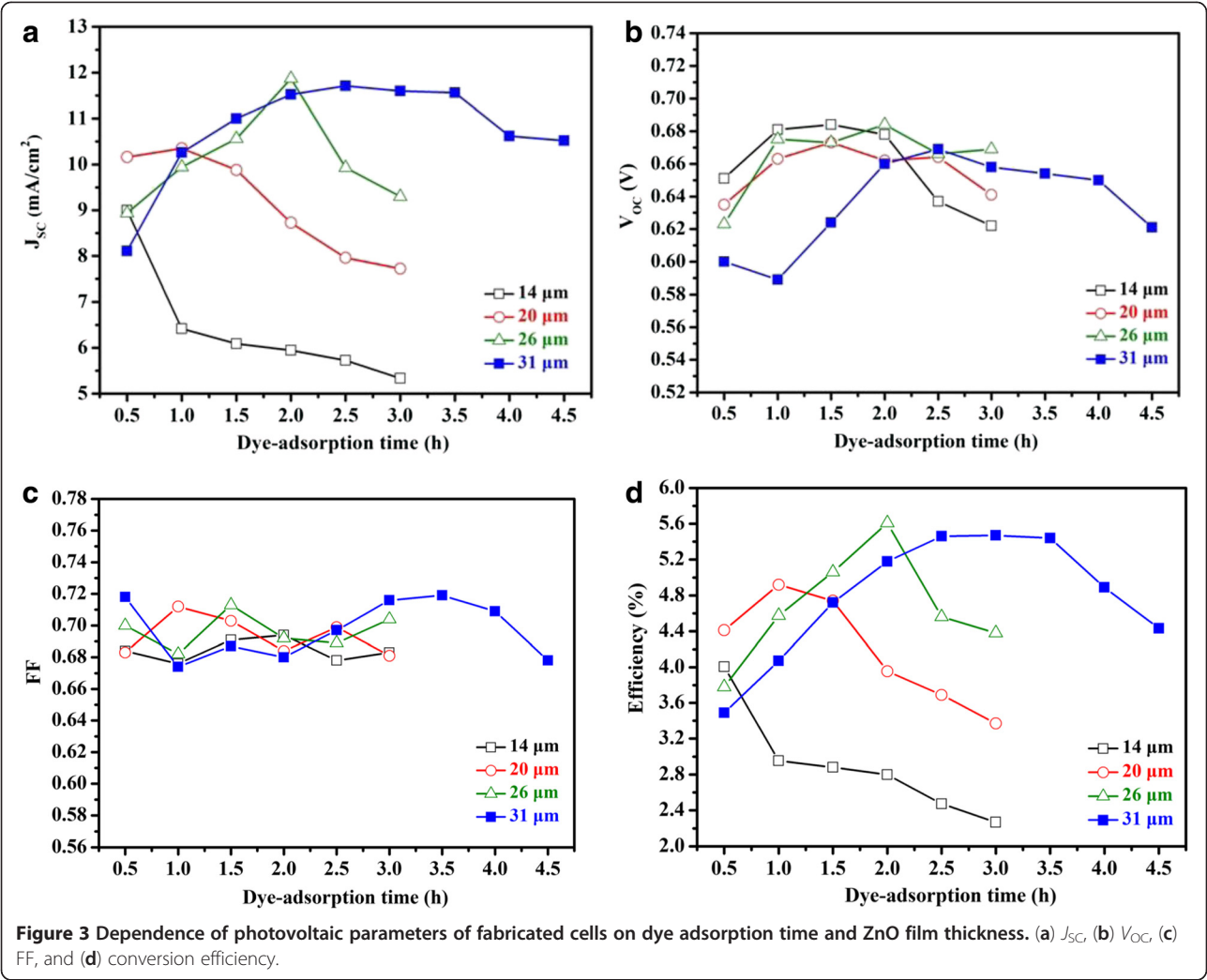
Photovoltaic characteristics of fabricated DSSCs

The performance of the fabricated DSSCs was measured under 1 sun AM 1.5 G simulated light. Figure 3 shows the dependence of various photovoltaic parameters on the dye adsorption time and the film thickness: J_{SC} , V_{OC} , fill factor (FF), and overall conversion efficiency. Figure 3a shows a plot of J_{SC} versus the dye adsorption time for various film thicknesses. Except for the thinnest photoanode (14 μ m), where the J_{SC} values decrease continuously with increasing dye adsorption time, the J_{SC} values of the remaining cells exhibit a similar trend with the dye adsorption time: the J_{SC} values first increase as the dye adsorption time increases, reach a peak value, and then decrease as the dye adsorption time increases. The initial rise in the J_{SC} values with increasing dye adsorption time is likely the result of increasing dye molecule adsorption on the ZnO film. However, when the dye adsorption time becomes too long, dye molecules can aggregate on the metal oxide surface, reducing J_{SC} [32,35-37]. Dye molecules exhibit slower electron

injection or self-quench if they undergo aggregation, which can occur either before or during dye adsorption on metal oxides [40]. Figure 3a also shows that different film thicknesses require different dye adsorption times to achieve their respective peak J_{SC} values. The dye adsorption time required to achieve the maximum J_{SC} value increased from 1 h for the 20- μ m photoelectrode to approximately 3 h for the 31- μ m photoelectrode. The 26- μ m photoelectrode achieved the highest J_{SC} .

Figure 3b presents a comparison of V_{OC} values of the fabricated devices. This figure shows that the V_{OC} values first increase with the dye adsorption time. After reaching a maximum V_{OC} value, a further increase in the adsorption time leads to a decline in the V_{OC} value. Similar to the J_{SC} plot, the adsorption time required to achieve the respective maximum V_{OC} increases as the film thickness increases. Figure 3b also shows that the maximum V_{OC} values decrease slightly as the film thickness increases. This is likely the result of increased charge recombination and more restricted mass transfer with thick films. As the film thickness increases, electrons encounter a longer transport distance and recombine more easily with I_3^- . This results in a stronger electron transfer resistance and a shorter electron lifetime in the ZnO film [31]. The FF values shown in Figure 3c exhibit no clear trends. The FF values vary between 0.67 and 0.72, which are relatively high compared to those reported for ZnO-based DSSCs [37,41].

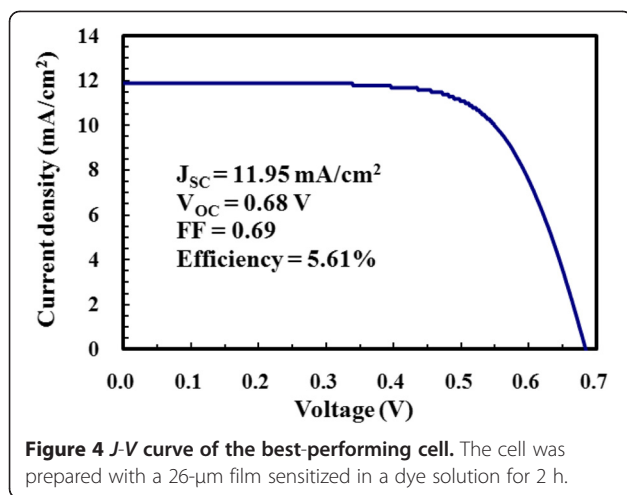
Based on these parameters, the overall conversion efficiencies at various dye adsorption times and film thicknesses were calculated. The efficiency plot (Figure 3d) closely resembles the J_{SC} plot (Figure 3a). Their trends are similar and their peak values appear at the same dye adsorption times. J_{SC} is the efficiency-determining parameter because the dye adsorption time has a considerably stronger effect on J_{SC} than on other photovoltaic parameters. Figure 3d also shows that each film thickness has a unique optimal dye adsorption time at which the maximum conversion efficiency occurs. The optimal dye adsorption time determined at a given film thickness does not apply to other thicknesses. This is because the dye adsorption time is either too short or too long for other film thicknesses, resulting in considerably lower efficiencies. For example, when a dye adsorption time of 3 h (optimal for the 31- μ m film) was applied to the 20- μ m film, the conversion efficiency dropped from the peak value of 4.95% to approximately 3.4%, representing a 31% drop. Prolonged dye adsorption times cause dye aggregation [32,35-38] and etching of the ZnO surface [39], both of which result in performance deterioration in ZnO-based DSSCs. Conversely, TiO₂-based DSSCs are typically less sensitive to prolonged sensitization times because of the higher chemical stability of TiO₂ [32-34]. For example, Lee et al. [33] reported similar dye loadings and conversion efficiencies



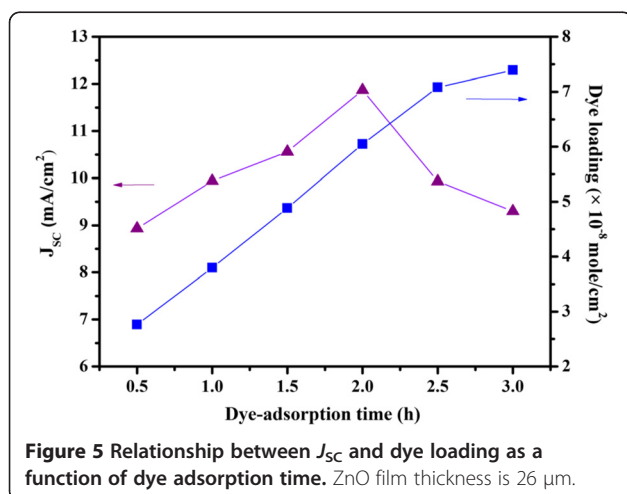
for TiO₂/N719-based DSSCs when the dye soaking time was extended from 2 to 24 h. Table 1 presents a summary of the photovoltaic characteristics of the best-performing cell for each film thickness, along with the corresponding optimal dye adsorption time. The optimal dye adsorption time varies with the film thickness; thicker films require longer dye adsorption times. In addition, the attainable conversion efficiency depends on the photoanode thickness. A photoanode that is too thin or too thick results in a lower conversion efficiency. This is because insufficient film thickness leads to a low interfacial surface area, whereas an

overly thick film aggravates unwanted charge recombination and poses more restriction on mass transfer [14,21,30,31]. Consequently, for the fabrication of ZnO/N719-based DSSCs, the dye adsorption time must be optimized simultaneously with the film thickness. A 26-μm-thick photoanode soaked in the dye solution for 2 h achieved the highest conversion efficiency (5.61%) of all the cells prepared in this study. Figure 4 shows the J - V curve of the best-performing cell measured under 1 sun AM 1.5 G simulated light. To better understand the effects of dye adsorption time on cell performance, this study also investigates dye

Table 1 Optimal dye adsorption times and photovoltaic characteristics of best-performing cell at each film thickness					
Film thickness (μm)	Optimal dye adsorption time (h)	Conversion efficiency (%)	Short-circuit photocurrent density (mA/cm ²)	Open circuit voltage (V)	Fill factor
14	0.5	3.98	9.00	0.65	0.68
20	1	4.92	10.35	0.66	0.72
26	2	5.61	11.95	0.68	0.69
31	3	5.47	11.60	0.66	0.72

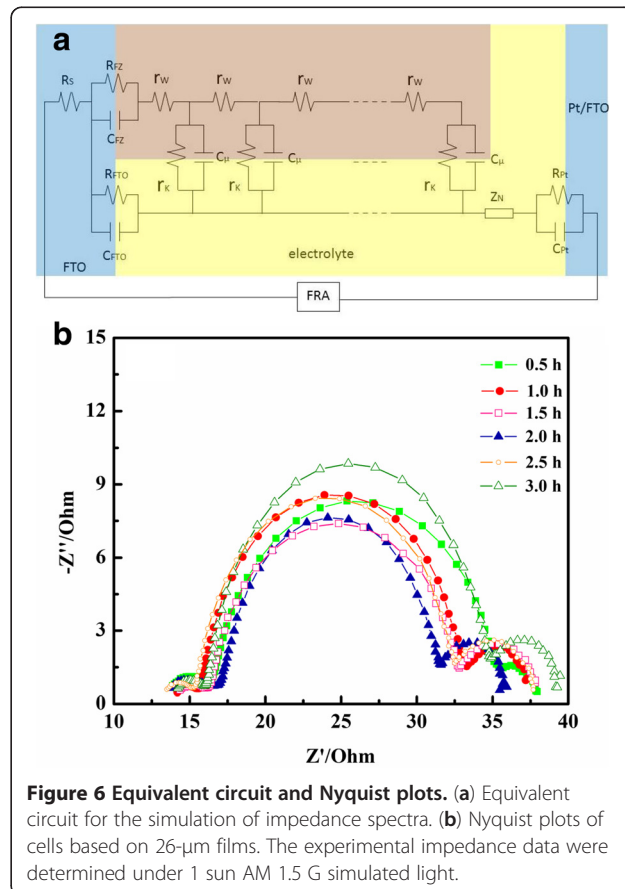


loading in cells based on 26- μm -thick films. Figure 5 shows the correlation between J_{SC} and dye loading as a function of dye adsorption time. The amount of adsorbed dye molecules increases continuously as the adsorption time increases, whereas the J_{SC} value reaches a maximum value and then decreases as the dye adsorption time increases. This observation is in contrast to that reported for TiO_2 -based DSSCs, where dye loading reached saturation after 2 h of sensitization and remained at the same level even when the sensitization time increased to 24 h [33]. The continuous increase of dye loading with sensitization time observed here suggests that the J_{SC} deterioration is the result of dye aggregation. In this study, the ZnO film was sensitized with the weak acidic N719 dye, which was adsorbed onto the surface of ZnO particles through the carboxylic acid anchoring group. Compared to TiO_2 , ZnO is less stable in acidic dyes. Thus, immersing ZnO in an acidic dye solution for a long period can lead to ZnO dissolution and the formation of Zn^{2+} /dye aggregates [32,35-37]. When dye aggregation



occurs, dye molecules exhibit slower electron injection and charge recombination aggravates, resulting in lower J_{SC} values [36,37].

To determine parameters related to electron transport and recombination, this study used EIS to analyze cells based on 26- μm -thick films. The experimental impedance data, given by the Nyquist plots in Figure 6b, were fitted to an equivalent circuit based on the diffusion-recombination model [42-44] (Figure 6a). The circuit elements related to the ZnO photoelectrode include the electron transport resistance within the ZnO mesoporous film (R_w) ($R_w = r_w L$, where L = film thickness), the charge transfer resistance (R_k) ($R_k = r_k/L$), which is related to the recombination of electrons at the ZnO/electrolyte interface, and the chemical capacitance of the ZnO electrode (C_μ) ($C_\mu = c_\mu L$). Additional circuit elements were introduced to modify the equivalent circuit model, as described in the following. The series resistance (R_s) represents total transport resistance of the FTO substrates and external circuits. Z_N is the impedance of the diffusion of I_3^- in the electrolyte. R_{Pt} and C_{Pt} are the resistance and the capacitance at the Pt/electrolyte interface, respectively. R_{FTO} and C_{FTO} are the resistance and the capacitance at the FTO/electrolyte interface, respectively. R_{FZ} and C_{FZ} represent the resistance and the capacitance at the FTO/ZnO interface, respectively.



The three fitted parameters of R_w , R_k , and C_μ can be used to calculate additional parameters, such as the mean electron lifetime (τ_{eff}), effective electron diffusion coefficient (D_{eff}), and effective electron diffusion length (L_{eff}), which are useful for evaluating cell performance.

The Nyquist plots in Figure 6b show the experimental impedance data obtained at various dye adsorption times. The impedance spectra of DSSCs generally exhibit three semicircles. The semicircle in the high-frequency range corresponds to charge transfer behavior at the Pt/electrolyte (R_{Pt} and C_{Pt}), the FTO/electrolyte (R_{FTO} and C_{FTO}), and the FTO/ZnO (R_{FZ} and C_{FZ}) interfaces. The semicircle in the mid-frequency range (the central arc) is assigned to the electron transfer at the ZnO/dye/electrolyte interfaces, which is related to R_w , R_k , and C_μ . The semicircle in the low-frequency range represents the Warburg diffusion process of I^-/I_3^- in the electrolyte (Z_N) [42-45].

Table 2 presents a summary of results from fitting the experimental impedance data to the equivalent circuit. The highest R_k/R_w value occurs at a dye adsorption time of 2 h, which is the optimal dye adsorption time for 26- μm -thick photoanodes. Both J_{SC} and conversion efficiency reach their maxima at this dye adsorption time (Figure 5). The high R_k/R_w value obtained at the optimal dye adsorption time suggests that a large number of electrons are injected into the photoelectrode [45,46]. The injected electrons undergo forward transport in the photoanode or recombine with I_3^- . This result explains the high J_{SC} value observed at the optimal dye adsorption time. In addition, the k_{eff} value can be estimated from the characteristic frequency at the top of the central arc ($k_{\text{eff}} = \omega_{\text{max}}$) of the impedance spectra. The parameter τ_{eff} was then estimated as the reciprocal of k_{eff} ($\tau_{\text{eff}} = 1/k_{\text{eff}}$) [45]. Table 2 shows that τ_{eff} reaches its highest value at a dye adsorption time of 2 h. Lower τ_{eff} values result at insufficient (<2 h) or prolonged dye adsorption times (>2 h). The trend observed here is unlike that of TiO_2 -based cells, whose photovoltaic performance and corresponding EIS spectra remain unchanged after an adsorption time of 12 h [34]. The resistance reaches a constant level once sufficient dye molecules are adsorbed onto the TiO_2 surfaces, and does

not increase at prolonged adsorption times. When the dye adsorption time is insufficient, the ZnO surface is not completely covered with the dye molecules, and certain areas are in direct contact with the electrolyte. Consequently, severe charge recombinations lead to low τ_{eff} and V_{OC} values. Prolonged dye adsorption times can lead to ZnO dissolution and the formation of Zn^{2+} /dye aggregates with acidic dyes [32,35-37], such as the N719 dye used in this study. Dye aggregation leads to slower electron injection and higher charge recombination [36,37]. The end result is a lower J_{SC} and overall conversion efficiency [39]. These reports support the trends of τ_{eff} and J_{SC} versus dye adsorption time observed in this study.

The effective electron diffusion time (τ_d) in the photoanodes is given by $\tau_d = \tau_{\text{eff}}/(R_k/R_w)$. The lowest τ_d also occurs at the optimal dye adsorption time of 2 h, indicating that the optimal dye adsorption time enhanced electron transport in the ZnO photoanode. Charge collection efficiencies (η_{CC}) were estimated using the relation $\eta_{\text{CC}} = 1 - \tau_d/\tau_{\text{eff}}$ [47]. Again, η_{CC} reaches its maximum value at the optimal dye adsorption time of 2 h, suggesting that using an appropriate dye adsorption time minimizes charge recombination.

The parameter D_{eff} was then calculated using the relation $D_{\text{eff}} = (R_k/R_w)(L^2/\tau_{\text{eff}})$, where L is the thickness of the ZnO film (26 μm). The highest D_{eff} value ($8.05 \times 10^{-3} \text{ cm}^2 \text{ s}^{-1}$) was also obtained at the optimal dye adsorption time of 2 h. This high D_{eff} value can be explained by more injected electrons and induced faster transport of electrons. The parameter L_{eff} calculated by the relation $L_{\text{eff}} = (D_{\text{eff}} \times \tau_{\text{eff}})^{1/2}$, reflects the competition between the collection and recombination of electrons. A cell fabricated using the optimal dye adsorption time of 2 h achieved the highest L_{eff} value of 111.6 μm , which exceeds the thickness of the photoelectrode (26 μm). This indicates that most of the injected electrons reached the FTO substrate before recombination occurred. This L_{eff} trend shows good agreement with that of J_{SC} . Increased recombination can explain the significant drop in J_{SC} values at other dye adsorption times. Overall, the EIS analysis results are in good agreement with the measured device performance parameters.

Table 2 Effects of dye adsorption time on electron transport properties of fabricated cells

Dye adsorption time (h)	R_k/R_w	Mean electron lifetime (ms)	Effective electron diffusion time (ms)	Charge collection efficiency (%)	Effective electron diffusion coefficient ($\times 10^{-3} \text{ cm}^2 \text{ s}^{-1}$)	Effective electron diffusion length (μm)
0.5	5.22	8.40	1.61	80.8	4.21	59.4
1	10.61	12.63	1.19	90.6	5.68	84.7
1.5	13.10	12.63	0.96	92.4	7.01	94.1
2	18.43	15.48	0.84	94.6	8.05	111.6
2.5	10.95	13.91	1.27	90.9	5.86	86.0
3	8.68	12.63	1.46	88.5	3.79	76.6

The thickness of the photoelectrode was 26 μm . R_k , charge transfer resistance at the ZnO/electrolyte interface; R_w , electron transport resistance in the ZnO network.

The DSSC prepared using the optimized fabrication condition (film thickness = 26 μm and dye adsorption time = 2 h) was also subjected to a long-term at-rest stability test, in which the cell was stored in the dark at room temperature. Figure 7 shows the changes in photovoltaic characteristics over time. The efficiency data shown in this figure are the average of three measurements. During the first 100 h, the device performance improved slightly. The power conversion efficiency increased from 4.76% to 5.61%, whereas J_{SC} rose from 10.9 to 11.78 mA/cm^2 . From 100 to 3000 h, the overall conversion efficiency gradually decreased to 3.39% because of the decline of J_{SC} , V_{OC} , and FF. Thereafter, the overall conversion efficiency remained nearly unchanged for 8,000 h, as did the J_{SC} , V_{OC} , and FF values. Although the fabricated cell used a liquid electrolyte, it

demonstrated excellent at-rest stability and retained approximately 70% of its initial efficiency after more than 1 year of storage.

Conclusions

In summary, this study reports the successful fabrication of DSSC photoelectrodes using commercially available ZnO particles sensitized with acidic N719 dye. The effects of two fabrication factors, the film thickness and the dye adsorption time, were systematically investigated. The results show that to obtain efficient ZnO/N719-based DSSCs, the dye adsorption time must be varied with the photoanode thickness. This is because the dye adsorption time suited for a particular film thickness does not apply to other film thicknesses. This is primarily because prolonged dye sensitization times

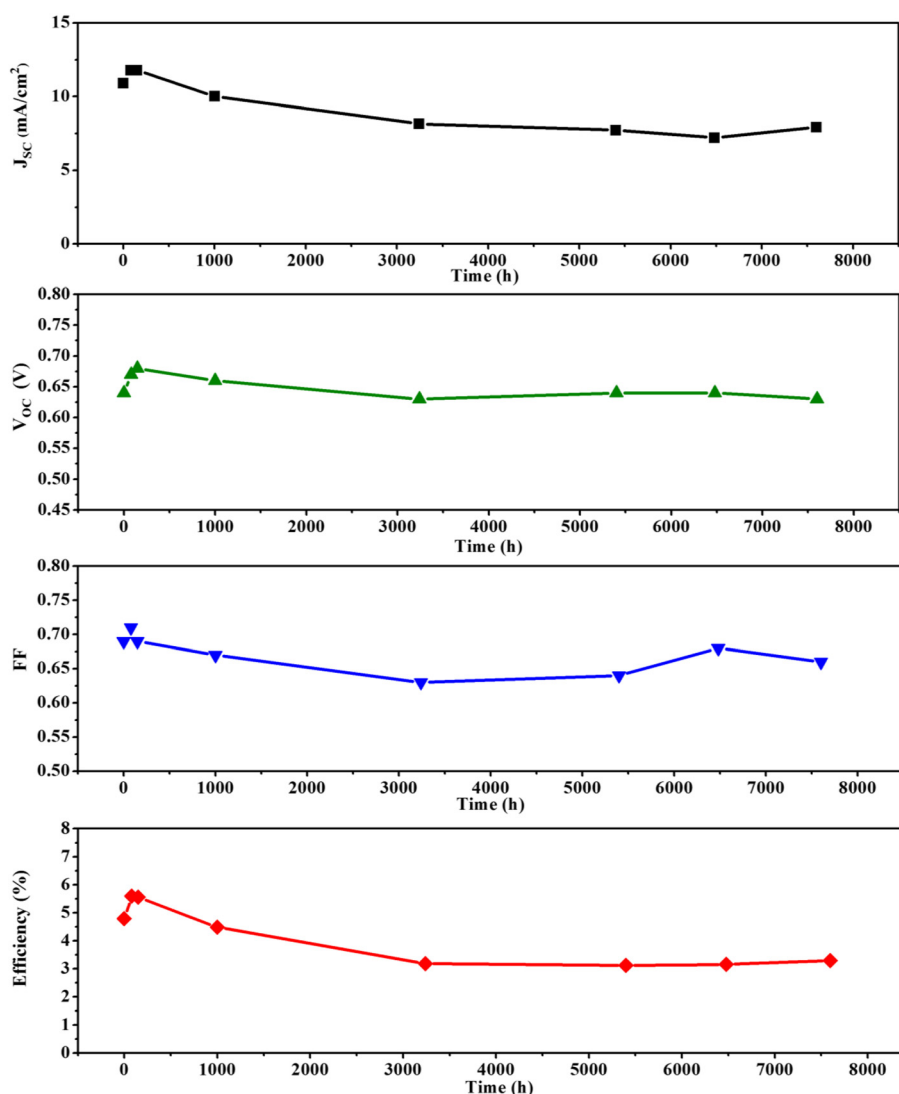


Figure 7 At-rest stability of the best-performing cell. The cell was prepared with a 26- μm film sensitized in a dye solution for 2 h.

lead to significant deterioration in the performance of ZnO-based cells. This is in contrast to the typical behavior for TiO₂-based cells, which usually adopt a single sufficiently long dye adsorption time for all film thicknesses. This is because TiO₂-based cells are generally insensitive to prolonged sensitization times because of the higher chemical stability of TiO₂. Through systematic optimization of the film thickness and the dye adsorption time, the highest overall conversion efficiency achieved in this study was 5.61%, obtained from a 26-μm photoelectrode sensitized for 2 h. The best-performing cell also showed remarkable at-rest stability, retaining approximately 70% of its initial efficiency after more than 1 year of room-temperature storage in the dark.

Abbreviations

AM: Air mass; DSSC: Dye-sensitized solar cells; EIS: Electrochemical impedance spectroscopy; FE-SEM: Field-emission scanning electron microscopy; FF: Fill factor; FTO: Fluorine-doped tin oxide; J_{SC} : Short-circuit photocurrent density; V_{OC} : Open circuit voltage; XRD: X-ray diffraction.

Competing interests

The authors declare that they have no competing interests.

Authors' contributions

WCC designed and performed the experiment, analyzed the data, and helped draft the manuscript. CML helped draft the manuscript. WCY conceived the study, participated in its design and coordination, and helped with the manuscript preparation. CHL helped draft the manuscript. All authors read and approved the final manuscript.

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